

Product Summary

Device	BV _{DSS}	R _{DS(on) Max}	I _{D Max} T _A = +25°C
01	20V	0.4Ω @ V _{GS} = 4.5V	1.34A
Q1		200	0.5Ω @ V _{GS} = 2.5V
		0.7Ω @ V _{GS} = -4.5V	-1.14A
Q2	-20V	0.9Ω @ V _{GS} = -2.5V	-0.94A

This MOSFET has been designed to minimize the on-state resistance

(R_{DS(on)}) and yet maintain superior switching performance, making it

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage V_{GS(TH)} < 1V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Complementary Pair MOSFET
- Ultra-Small Surface Mount Package
- ESD Protected Gate to 2.5kV HBM
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMC2700UDMQ</u>)

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.015 grams (Approximate)



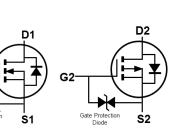
Description and Applications

Portable Electronics

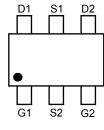
ideal for high-efficiency power management applications.

SOT26

Top View



Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DMC2700UDM-7	C27	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

G1

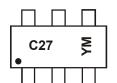
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



C27 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2009		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	W			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings N-CHANNEL – Q1 (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain Source Voltage		V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±6	V
Drain Current (Note 5)	$ T_A = +25^{\circ}C T_A = +85^{\circ}C $		1.34 0.97	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	5	А
Pulsed Body Diode Forward Current (10µs Pulse, Du	ity Cycle = 1%)	I _{SM}	5	А

Maximum Ratings P-CHANNEL – Q2 (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain Source Voltage	V _{DSS}	-20	V	
Gate-Source Voltage		V _{GSS}	±6	V
Drain Current (Note 5)	T _A = +25°C T _A = +85°C	ID	-1.14 -1.07	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-2.5	А	
Pulsed Body Diode Forward Current (10µs Pulse, Du	ity Cycle = 1%)	I _{SM}	-2.5	А

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1.12	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	111	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. For a device mounted on 25mm x 25mm FR-4 PCB board with a high coverage of single sided 1oz copper, in still air conditions with two active die.



Electrical Characteristics N-CHANNEL – Q1 (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	_		V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current	IDSS	_		100	nA	V _{DS} = 20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	_	_	±1.0	μA	V_{GS} = ±4.5V, V_{DS} = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	0.5		1.0	V	V _{DS} = V _{GS} , I _D = 250µA
Static Drain-Source On-Resistance	R _{DS(on)}		0.3 0.4 0.5	0.4 0.5 0.7	Ω	V_{GS} = 4.5V, I _D = 600mA V_{GS} = 2.5V, I _D = 500mA V_{GS} = 1.8V, I _D = 350mA
Forward Transfer Admittance	Y _{fs}	_	1.4		S	V _{DS} = 10V, I _D = 400mA
Diode Forward Voltage (Note 6)	V _{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 150mA
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	_	60.67	_	pF	
Output Capacitance	C _{oss}	_	9.68	_	pF	V _{DS} = 16V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	5.37	_	pF	
Total Gate Charge	Qg		736.6			
Gate-Source Charge	Q _{gs}		93.6		рС	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}		116.6			I _D = 250mA
Turn-On Delay Time	t _{D(on)}		5.1			
Turn-On Rise Time	t _R		7.4			$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(off)}		26.7		ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$
Turn-Off Fall Time	tF		12.3			I _D = 200mA

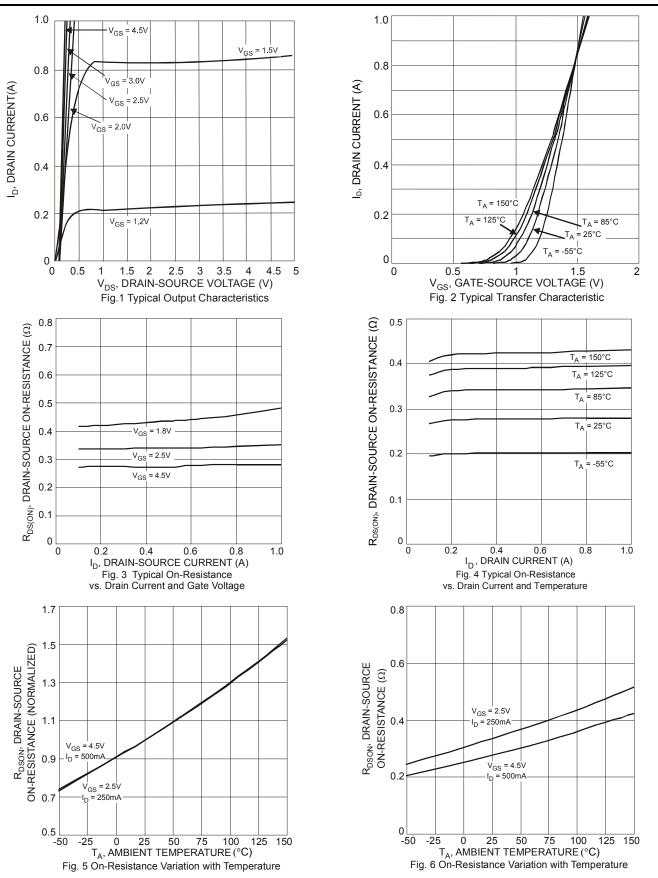
Electrical Characteristics P-CHANNEL – Q2 (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	-		- 76		1 0.000	
Drain-Source Breakdown Voltage	BV _{DSS}	-20			V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current	IDSS	_	_	-100	nA	V _{DS} = -20V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}		_	±1.0	μA	V_{GS} = ±4.5V, V_{DS} = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	-0.5		-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	6		0.5 0.7	0.7 0.9	Ω	$V_{GS} = -4.5V, I_D = -430mA$
	R _{DS(on)}	_	1.0	1.3	12	V _{GS} = -2.5V, I _D = -300mA V _{GS} = -1.8V, I _D = -150mA
Forward Transfer Admittance	Y _{fs}	_	-0.9	_	S	V _{DS} = -10V, I _D = -250mA
Diode Forward Voltage (Note 6)	V _{SD}	_	-0.8	-1.2	V	V _{GS} = 0V, I _S = -150mA
DYNAMIC CHARACTERISTICS						-
Input Capacitance	C _{iss}		59.76	_	pF	
Output Capacitance	C _{oss}		12.07	_	pF	V _{DS} = -16V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}		6.36		pF	
Total Gate Charge	Qg		622.4	_		
Gate-Source Charge	Q _{gs}		100.3	_	рС	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -250mA
Gate-Drain Charge	Q _{gd}		132.2	_		$I_D = -23011A$
Turn-On Delay Time	t _{D(on)}		5.1			
Turn-On Rise Time	t _R		8.1			$V_{DD} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t _{D(off)}		28.4	_	ns	R _L = 47Ω, R _G = 10Ω, I _D = -200mA
Turn-Off Fall Time	t _F	_	20.7	_		

Note: 6. Short duration pulse test used to minimize self-heating effect.

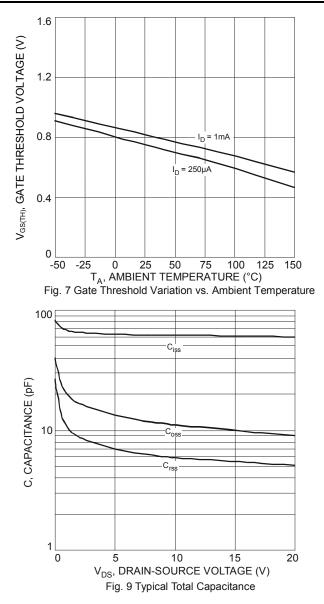


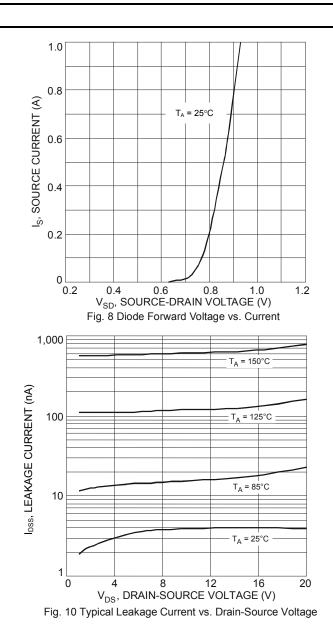
N-CHANNEL - Q1





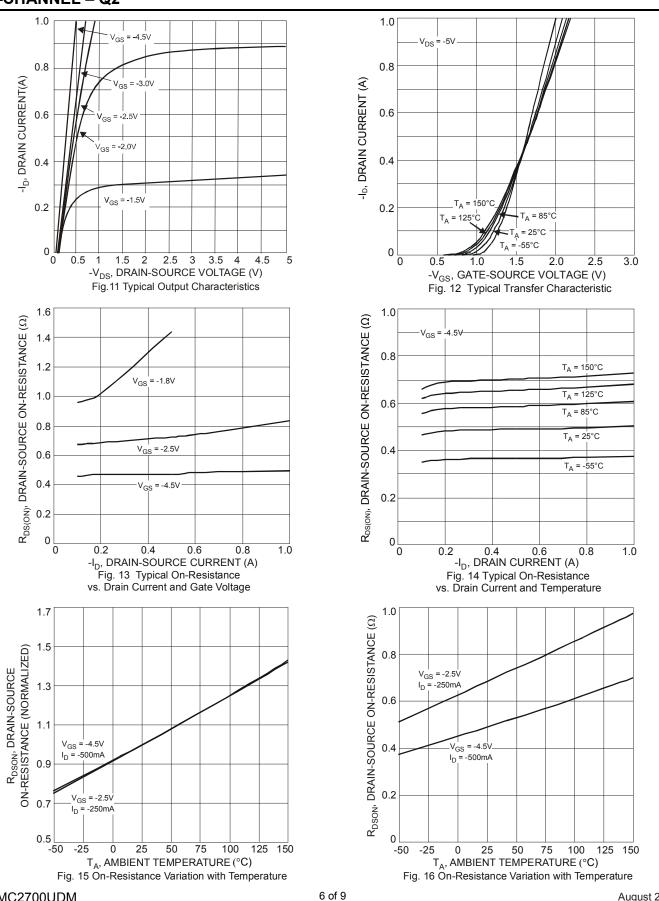
N-CHANNEL – Q1 (continued)







P-CHANNEL – Q2

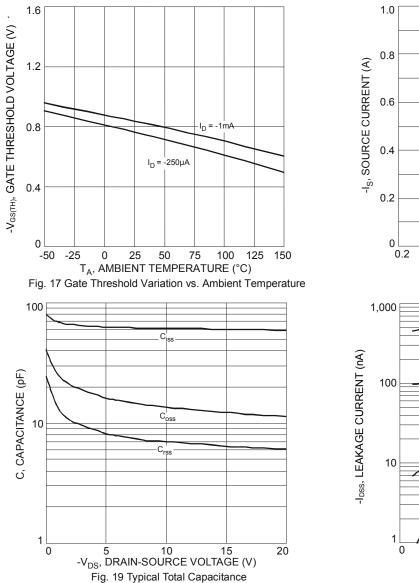


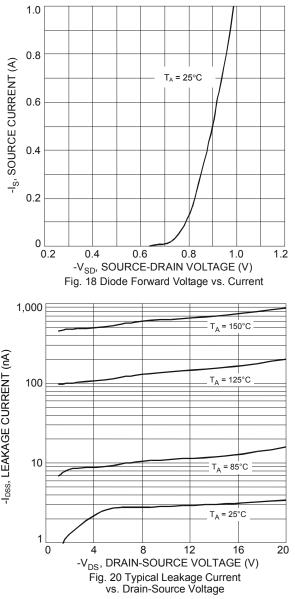
DMC2700UDM Document number: DS35360 Rev. 3 - 2

Downloaded From Oneyac.com



P-CHANNEL – Q2 (continued)

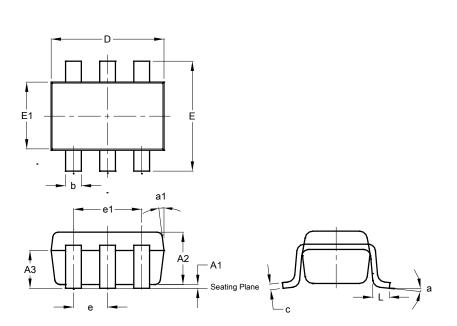






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



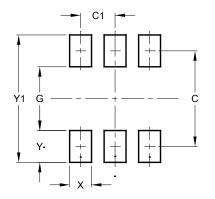
	SC	DT26	
Dim	Min	Max	Тур
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
С	0.10	0.20	0.15
D	2.90	3.10	3.00
е	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
а	-	-	8°
a1	-	-	7°
All	Dimen	sions	in mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26

SOT26



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5 products provided subject to Diodes' Standard Terms and Conditions of Sale Diodes are (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))